

SILICON POWER TRANSISTOR
2SC2335NPN SILICON TRIPLE DIFFUSED TRANSISTOR
FOR HIGH-SPEED HIGH-VOLTAGE SWITCHING

The 2SC2335 is a mold power transistor developed for high-speed high-voltage switching, and is ideal for use as a driver in devices such as switching regulators, DC/DC converters, and high-frequency power amplifiers.

FEATURES

- Low collector saturation voltage: $V_{CE(sat)} = 1.0 \text{ V MAX. @ } I_C = 3.0 \text{ A}$
- Fast switching speed: $t_r = 1.0 \mu\text{s MAX. @ } I_C = 3.0 \text{ A}$
- Wide base reverse-bias SOA: $V_{CEX(SUS)1} = 450 \text{ V MIN. @ } I_C = 3.0 \text{ A}$

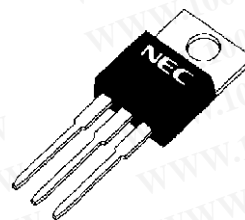
ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

| Parameter | Symbol | Conditions | Ratings | Unit |
|------------------------------|----------------|---|-------------|------------------|
| Collector to base voltage | V_{CBO} | | 500 | V |
| Collector to emitter voltage | V_{CEO} | | 400 | V |
| Emitter to base voltage | V_{EBO} | | 7.0 | V |
| Collector current (DC) | $I_{C(DC)}$ | | 7.0 | A |
| Collector current (pulse) | $I_{C(pulse)}$ | $PW \leq 300 \mu\text{s}$, duty cycle $\leq 10\%$ | 15 | A |
| Base current (DC) | $I_{B(DC)}$ | | 3.5 | A |
| Total power dissipation | P_T | $T_C = 25^\circ\text{C}$ | 40 | W |
| | | $T_A = 25^\circ\text{C}$ | 1.5 | W |
| Junction temperature | T_j | | 150 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | | -55 to +150 | $^\circ\text{C}$ |

ORDERING INFORMATION

| Part No. | Package |
|----------|----------|
| 2SC2335 | TO-220AB |

(TO-220AB)



勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-54151736
 勝特力电子(深圳) 86-755-83298787
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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

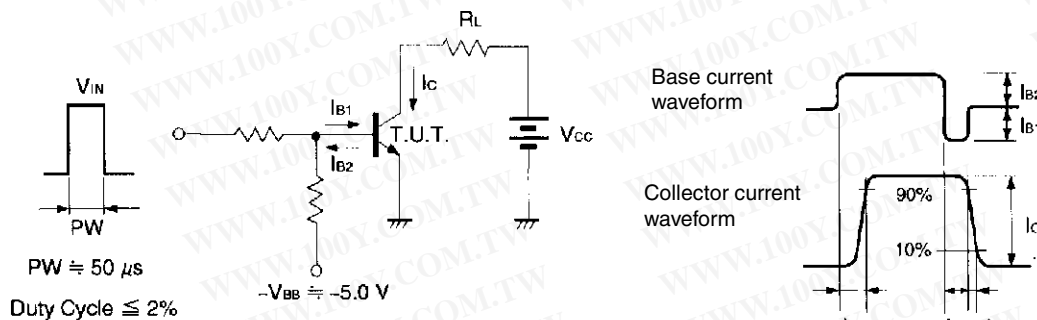
| Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|------------------------------|-----------------|---|------|------|------|---------------|
| Collector to emitter voltage | $V_{CE0(SUS)}$ | $I_C = 3.0\text{ A}$, $I_{B1} = 0.6\text{ A}$, $L = 1\text{ mH}$ | 400 | | | V |
| Collector to emitter voltage | $V_{CEX(SUS)1}$ | $I_C = 3.0\text{ A}$, $I_{B1} = -I_{B2} = 0.6\text{ A}$, $V_{BE(OFF)} = -5.0\text{ V}$, $L = 180\text{ }\mu\text{H}$, clamped | 450 | | | V |
| Collector to emitter voltage | $V_{CEX(SUS)2}$ | $I_C = 6.0\text{ A}$, $I_{B1} = 2.0\text{ A}$, $-I_{B2} = 0.6\text{ A}$, $V_{BE(OFF)} = -5.0\text{ V}$, $L = 180\text{ }\mu\text{H}$, clamped | 400 | | | V |
| Collector cutoff current | I_{CBO} | $V_{CB} = 400\text{ V}$, $I_E = 0\text{ A}$ | | | 10 | μA |
| Collector cutoff current | I_{CER} | $V_{CE} = 400\text{ V}$, $R_{BE} = 51\text{ }\Omega$, $T_A = 125^\circ\text{C}$ | | | 1.0 | mA |
| Collector cutoff current | I_{CEX1} | $V_{CE} = 400\text{ V}$, $V_{BE(OFF)} = -1.5\text{ V}$ | | | 10 | μA |
| Collector cutoff current | I_{CEX2} | $V_{CE} = 400\text{ V}$, $V_{BE(OFF)} = -1.5\text{ V}$, $T_A = 125^\circ\text{C}$ | | | 1.0 | mA |
| Emitter cutoff current | I_{EBO} | $V_{EB} = 5.0\text{ V}$, $I_C = 0\text{ A}$ | | | 10 | μA |
| DC current gain | h_{FE1} | $V_{CE} = 5.0\text{ V}$, $I_C = 0.1\text{ A}$ ^{Note} | 20 | | 80 | |
| DC current gain | h_{FE2} | $V_{CE} = 5.0\text{ V}$, $I_C = 1.0\text{ A}$ ^{Note} | 20 | | 80 | |
| DC current gain | h_{FE3} | $V_{CE} = 5.0\text{ V}$, $I_C = 3.0\text{ A}$ ^{Note} | 10 | | | |
| Collector saturation voltage | $V_{CE(sat)}$ | $I_C = 3.0\text{ A}$, $I_B = 0.6\text{ A}$ ^{Note} | | | 1.0 | V |
| Base saturation voltage | $V_{BE(sat)}$ | $I_C = 3.0\text{ A}$, $I_B = 0.6\text{ A}$ ^{Note} | | | 1.2 | V |
| Turn-on time | t_{on} | $I_C = 3.0\text{ A}$, $R_L = 50\text{ }\Omega$, $I_{B1} = -I_{B2} = 0.6\text{ A}$, $V_{CC} \equiv 150\text{ V}$ | | | 1.0 | μs |
| Storage time | t_{stg} | Refer to the test circuit. | | | 2.5 | μs |
| Fall time | t_f | | | | 1.0 | μs |

Note Pulse test $PW \leq 350\text{ }\mu\text{s}$, duty cycle $\leq 2\%$

h_{FE} CLASSIFICATION

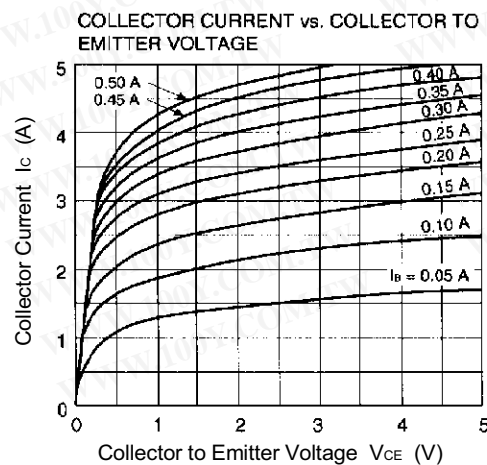
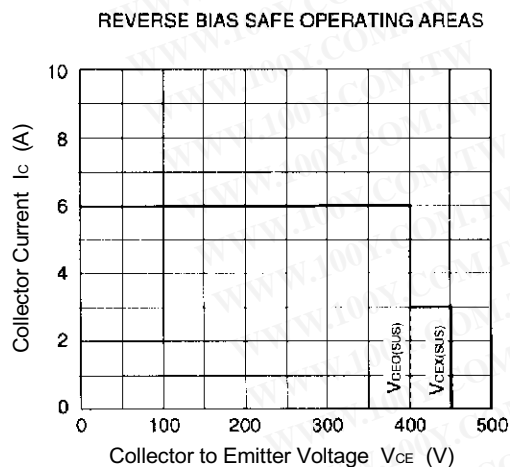
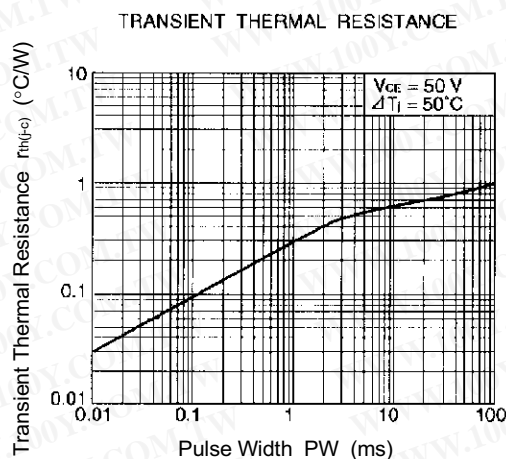
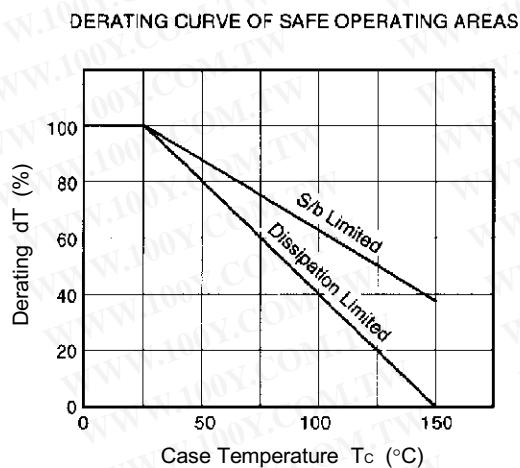
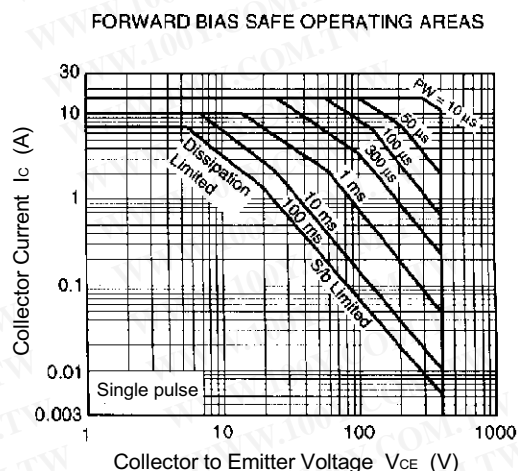
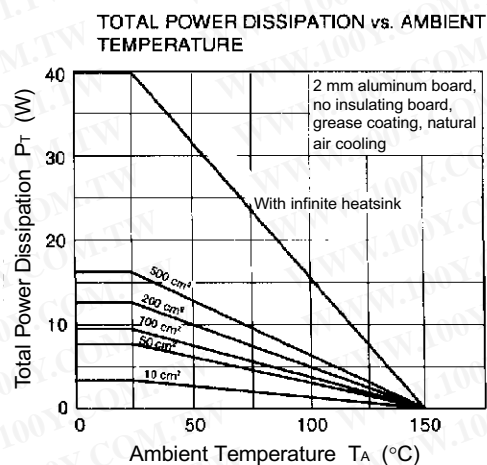
| Marking | M | L | K |
|-----------|----------|----------|----------|
| h_{FE2} | 20 to 40 | 30 to 60 | 40 to 80 |

SWITCHING TIME (t_{on} , t_{stg} , t_f) TEST CIRCUIT



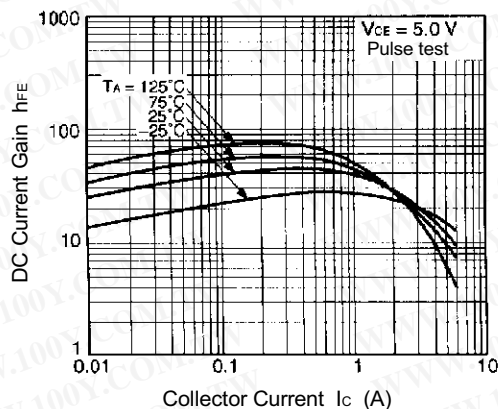
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TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)

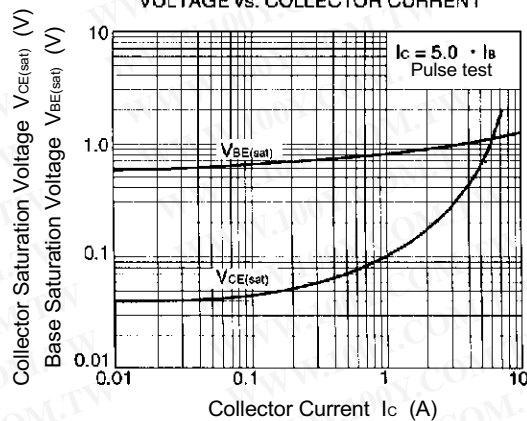


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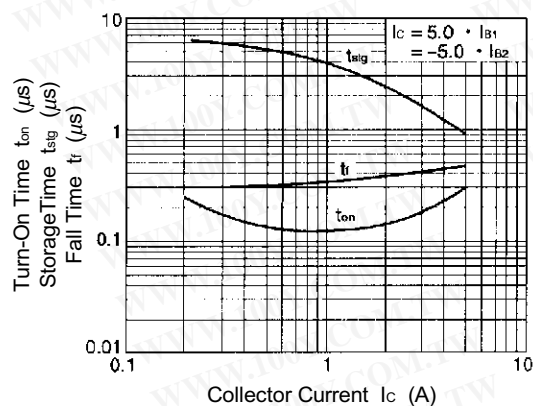
DC CURRENT GAIN vs. COLLECTOR CURRENT



BASE AND COLLECTOR SATURATION VOLTAGE vs. COLLECTOR CURRENT



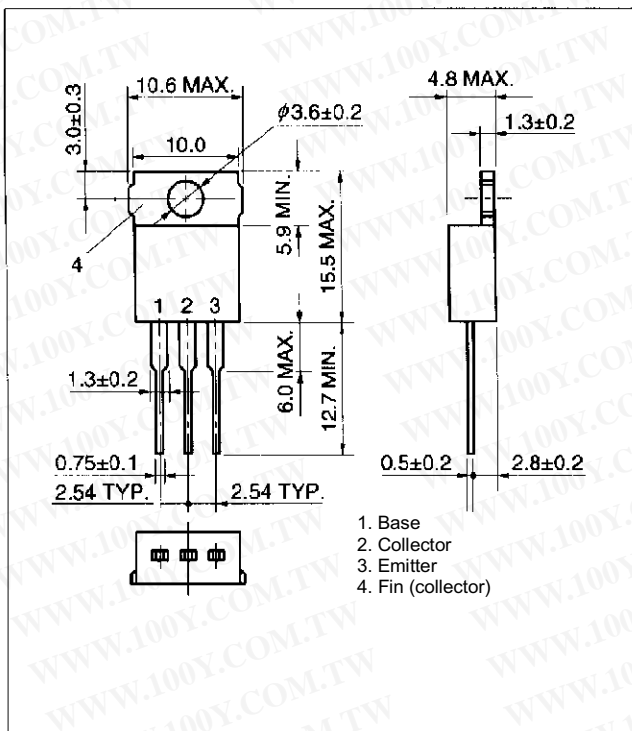
TURN ON TIME, STORAGE TIME AND FALL TIME vs. COLLECTOR CURRENT



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PACKAGE DRAWING (UNIT: mm)

TO-220AB (MP-25)



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